Supercond. Sci. Technol. 27 (2014) 115003 (7pp)

The effect of Cr impurity to superconductivity in electron-doped $BaFe_{2-x}Ni_xAs_2$

Rui Zhang¹, Dongliang Gong¹, Xingye Lu¹, Shiliang Li^{1,3}, Pengcheng Dai^{1,2} and Huiqian Luo¹

¹ Beijing National Laboratory for Condensed Matter Physics, Institute of Physics, Chinese Academy of Sciences, Beijing 100190, People's Republic of China
² Department of Physics and Astronomy, Rice University, Houston, Texas 77005, USA
³ Collaborative Innovation Center of Quantum Matter, Beijing, People's Republic of China

E-mail: hqluo@iphy.ac.cn

Received 3 July 2014, revised 25 August 2014 Accepted for publication 2 September 2014 Published 22 September 2014

Abstract

We use transport and magnetization measurements to study the effect of Cr-doping to the phase diagram of the electron-doped superconducting $BaFe_{2-x}Ni_xAs_2$ iron pnictides. In principle, adding Cr to electron-doped $BaFe_{2-x}Ni_xAs_2$ should be equivalent to the effect of hole-doping. However, we find that Cr doping suppresses superconductivity via impurity effect, while not affecting the normal state resistivity above 100 K. We establish the phase diagram of Cr-doped $BaFe_{2-x-y}Ni_xCr_yAs_2$ iron pnictides, and demonstrate that Cr-doping near optimal superconductivity restore the long-range antiferromagnetic order suppressed by superconductivity.

Keywords: iron-based superconductor, impurity, transport properties, phase diagram

(Some figures may appear in colour only in the online journal)

1. Introduction

A determination of the impurity effect on high-temperature (high- T_c) superconductors is important for establishing the microscopic origin of superconductivity in these materials [1]. For high- T_c copper oxide superconductors, nonmagnetic impurities such as Zn doped into the CuO₂ plane dramatically suppress superconductivity and induce antiferromagnetic (AF) excitations in hole-doped superconductors [2]. In the case of iron pnictides, electron-doping into the parent compounds can simultaneously suppress antiferromagnetic (AF) order and induce superconductivity [3-5]. For the electron doped BaFe_{2-x}Ni_xAs₂, extensive transport, x-ray and neutron diffraction measurements have established the overall structural and magnetic phase diagram [6-12]. For samples near optimal superconductivity, an incommensurate AF shortrange ordered phase was found to coexist and compete with superconductivity [10, 13]. Instead of originating from a spindensity-wave order from nested Fermi surfaces between the hole and electron pockets [13], the incommensurate AF shortrange order was found to be consistent with a cluster spin glass mesoscopically coexisting with superconductivity [12]. If this is indeed the case, it would be interesting to determine the ground state of the system when superconductivity is eliminated, as this could potentially reveal the presence of an avoided quantum critical point in the system [11].

One way to suppress superconductivity is by applying a magnetic field, and our previous elastic neutron scattering experiment indeed show that a field suppresses superconductivity also enhances the incommensurate AF order, confirming the competing nature of the incommensurate AF phase with superconductivity [10]. However, the maximum field one can apply in a scattering experiment is well below the upper critical field H_{c2} in iron pnictide superconductors [14] and an external magnetic field may also induce new electronic phases not present in the zero field [15]. Alternatively, superconductivity may be suppressed by the impurity substitutions in the conductance plane. In the case of



Figure 1. Three dimensional superconducting dome for BaFe_{2-x-y} Ni_xCr_yAs₂ as a function of Ni doping x and Cr impurity y.

copper oxide superconductors, a small amount of impurity such as Zn, Ni, Mn, and Fe in the CuO₂ plane can completely eliminate superconductivity, leading to new electronic states [16–18]. For superconducting iron pnictides, previous studies on the impurity effects mainly focus on the Zn, Mn, Cu, Ni and Ru substitution of Fe [19–26]. However, the T_c suppression rate (reduction of T_c for per percent concentration of impurity) of most impurities is lower than that of the cuprates, leading to the conclusion that superconducting electron pairing is inconsistent with quasiparticle excitations from the nested hole and electron Fermi surfaces [27–29]. Compared with other impurities, substituting Mn into optimally doped superconductor $Ba_{0.5}K_{0.5}Fe_2As_2$ has the largest superconducting suppression effect at about 7 K per 1% Mn substitution [22].

In this article, we report transport and bulk magnetic measurements on the Cr-doped superconducting $BaFe_{2-x}$ Ni_xAs₂. By carrying out systematic transport measurements on BaFe_{2-x-y}Ni_xCr_yAs₂ single crystals with different Ni and Cr concentrations, we are able to map out the evolution of superconducting dome as a function of the Ni doping and Cr concentration (figure 1). We find that optimal superconductivity in BaFe_{2-x}Ni_xAs₂ with maximum $T_c = 20$ K can be completely suppressed by 1.5% Cr doping (y = 0.03), leading to a T_c suppression rate of 13 K per 1% Cr-doping, much larger than that of Mn-doped iron pnictide [22]. From the temperature dependence of the resistivity measurements on BaFe_{2-x-v}Ni_xCr_vAs₂, we find that Cr doping does not affect T_N , T_s , and the normal state resistivity above 100 K in the underdoped compounds x = 0.049 and 0.066 until superconductivity is completely suppressed. In the optimal doped sample x = 0.082, T_N firstly decreases with increasing Cr doping and then increases upon further Cr substitution. For the electron overdoped sample with x = 0.098, increasing Cr doping to $y \ge 0.033$ may induce AF order. Our results suggest that Cr doping is effective in suppressing superconductivity, and the transport measurements provide the basis for future neutron scattering experiments detailing the relationship between magnetism and superconductivity.

2. Experiment

Single crystals of BaFe_{2-x-v}Ni_xCr_vAs₂ were grown by selfflux method similar to $BaFe_{2-x}Ni_xAs_2$ and $Ba_{1-x}K_xFe_2As_2$ [9, 30]. The precursors FeAs, NiAs and CrAs were prepared by solid-state reaction between Fe/Ni/Cr powder and ground As chips at 700-900 °C. In order to obtain a homogeneous mixture for the flux, all three precursors were mixed in the appropriate proportions (see table 1) and heated at 900-950 °C for 20 hrs, this procedure was repeated for three times. After this, the mixture of Ba pieces and FeNiCrAs flux (in the ratio of 1:5) was loaded into an aluminum oxide crucible and sealed in an evacuated quartz tube. The sealed quartz tube was heated up to 950 °C in a box furnace, holding for more than 10 hours to completely melt Ba. The system was then heated to 1180 °C in 12 hours and held for 10 hours to melt flux, following by cooling down to 1050 °C at a rate of 5 °C/h and finally quenched to room temperature. In-situ annealing with flux was tried at 800 °C for 20 hrs, which did not significantly affect on the superconductivity.

The crystallinity was examined by a Photonic Sciences Laue camera and a Mac-Science MXP18A-HF equipment for x-ray diffraction. The superconducting properties the samples were determined by the DC magnetization measurement using a Quantum Design SQUID Magnetic Property Measurement System (MPMS). To minimize the effect from geometry and demagnetization factor, we applied a small DC field (H = 10 or 20 Oe) parallel to *ab*-plane and measured using a zero-field cooled protocol. Resistance measurements were carried out on a Quantum Design Physical Property Measurement System (PPMS) by the standard four-probe method. The measured crystals were cut into rectangluar shapes $3 \times 1 \times 0.1 \text{ mm}^3$ with the *c*-axis being the smallest dimension. Four Ohmic contacts with low resistance (less than 1 Ω) on *ab*-plane were made by silver epoxy. In order to reduce noises, a large current I = 5 mA and slow sweeping rate of temperature (2 K/min) were applied.

3. Result and discussion

Large single crystals sized up to 15 mm can be cleaved from the as-grown ingot, as shown in figure 2 (a). To characterize the quality of our samples, we have performed x-ray diffraction and Laue reflection with incident beam parallels to caixs. Figure 2 (b) shows the clear pattern with four-fold spots from Laue reflection, where the arrows mark the [1, 0, 0] and [1, 1, 0] directions. Figure 2(c) shows the x-ray diffraction patterns for the sample with x = 0.082 and y = 0, 0.014, 0.020,0.027, 0.034 measured at room temperature. All sharp peaks with even index indicate high *c*-axis orientation and crystalline quality of our samples. Since Cr substitution is within Fe-As plane, the *c*-axis does not have significant change for different Cr concentrations, resulting in similar sets of x-ray diffraction data.

The chemical compositions of our crystals are determined by the inductively coupled plasma (ICP) analysis. By



Figure 2. (a) Picture of as-grown $BaFe_{2-x-y}Ni_xCr_yAs_2$ single crystals. (b) Laue reflection pattern of our crystal. (c) Typical patterns of X-ray diffraction on the single crystal $BaFe_{2-x-y}$ $Ni_xCr_yAs_2$ with x = 0.082 and y = 0, 0.014, 0.020, 0.027, 0.034. For clarity, the intensity is normalized to [0, 1] and shift upward in 0.2 for each compound.

assuming As positions are fully occupied at 2, we can estimate the ratio of Ba : Fe : Ni : Cr as summarized in tabel 1. The large deviation of Ba composition away from 1 in several samples is due to residual flux mixed in the samples, which is very common in the self-flux method and does not affect the calculated result of the Ni and Cr concentration. Statistically, the segregation coefficient, namely the ratio between real composition and nominal concentration, $K = C_s/C_l$ for Ni and Cr is about 0.82 ± 0.10 and 0.68 ± 0.11 , respectively, which is consistent with previous reports on the electron doped Ba-122 system [8, 9]. In the following discussions of this paper, we use the real composition of Ni doping *x* and Cr doping *y* to label all compounds.

Figure 3 shows the DC susceptibility data for the superconducting samples, where the magnetic signals are normalized by the susceptibility χ_0 at based temperature (2 K or 5 K). Since the Cr atom has two electrons less than Fe, one would expect hole doping effects in Cr substituted samples [31], contrasting to the electron doping effect in Ni substituted samples [8]. If this is indeed the case, adding equivalent amount of Cr as Ni to the electron-doped $BaFe_{2-x}Ni_xAs_2$ should bring the system back to the undoped AF state. We find that this is clearly not the case. Instead, superconductivity can be easily suppressed by a small amount of Cr doping, suggesting that the Cr doping acts as an impurity, similar to the cases in Ni or Co doped Ba_{0.5}K_{0.5}Fe₂As₂ [22]. In the optimally doped BaFe_{2-x}Ni_xAs₂ with x = 0.082, the maximum T_c is about 20.1 K in the Cr free sample. Substituting 0.35 % Cr with y = 0.007 in BaFe_{2-x-v}Ni_xCr_vAs₂, T_c quickly decreases to 15.2 K. No superconductivity above 0.05 K is found in the compounds with x = 0.082 and y = 0.027, indicating that 1.5 % Cr can suppress optimal superconductivity in BaFe_{2-x}Ni_xAs₂ system. Such large T_c suppression rate (about 13 K/%) is similar to the impurity effect to superconductivity in the hole-doped 122-type iron-based superconductors [19, 21–24]. Surprisingly, the superconducting transition width, defined as the temperature difference between 10 % and 90 % of χ_0 , is within 2 K in the entire Cr doping range, suggesting high quality of superconductivity in our samples.

To further investigate the normal state behavior in the Cr impurity substituted BaFe_{2-x-y}Ni_xCr_yAs₂ single crystals, we have performed systematic resistance measurements on all the compounds up to 300 K. figures 3(a)–(e) show temperature dependence of the resistivity data normalized by the room temperature resistivity *R* (300 K) to remove the uncertainty in estimating the absolute value due to geometric factors. The systematic decrease of T_c with increasing Cr doping confirms the magnetization measurements. Moreover, the temperature

Table 1. Real composition of $BaFe_{2-x-y}Ni_xCr_yAs_2$ single crystals from ICP analysis.

Nominal y/x	Ba	Fe	Ni	Cr	As	K(Ni)	<i>K</i> (Cr)
0.006/0.06	0.76	1.92	0.06	0.004	2	1.00	0.67
0.012/0.06	0.98	1.90	0.04	0.006	2	0.67	0.50
0.008/0.08	0.96	1.92	0.06	0.006	2	0.75	0.75
0.016/0.08	0.94	1.90	0.06	0.012	2	0.75	0.75
0.024/0.08	0.90	1.90	0.06	0.016	2	0.75	0.67
0.01/0.1	0.98	1.90	0.08	0.006	2	0.80	0.60
0.02/0.1	0.98	1.88	0.08	0.014	2	0.80	0.70
0.03/0.1	1.00	1.90	0.08	0.02	2	0.80	0.67
0.04/0.1	0.96	1.86	0.08	0.02	2	0.80	0.50
0.05/0.1	0.98	1.86	0.08	0.04	2	0.80	0.80
0.024/0.12	0.52	1.84	0.12	0.02	2	1.00	0.83
0.036/0.12	0.68	1.84	0.12	0.02	2	1.00	0.56
0.048/0.12	0.84	1.84	0.10	0.04	2	0.83	0.83
0.015/0.15	0.88	1.84	0.12	0.01	2	0.80	0.67
0.03/0.15	0.84	1.84	0.12	0.02	2	0.80	0.67



Figure 3. Magnetization and T_C for all superconducting compounds. All signals are normalized by the data χ_0 at based temperature (2 K or 5 K).

dependence of in-plane resistance are almost identical for temperatures above 100 K in the same batch of Ni doping x. This is clearly seen in the first derivative of the resistance data [figures 4 (f)–(j)], where all the normalized dR/dT curves overlap above 100 K for the same Ni concentration. This suggests that the normal state resistivity behavior is not much affected by the doped Cr impurity. If the temperature dependence of the resistivity suggests the presence of a quantum critical point, one should observe linear dependence of resistance or flat temperature dependent region in dR/dT. Inspection of figures 4(f)–(j) reveals $R \sim T^2$ behavior in the electron overdoped regime typical of Fermi liquid.

The temperature dependence of the resistivity below 100 K reveals a slight upturn consistent with the Cr impurity scattering. From the weak anomalies in the temperature dependence of the resistivity [9, 32], we can identify the AF and tetragonal to orthorhombic structural transitions. The two dips in dR/dT correspond to T_N and T_s marked as arrows in figure 4 (f)–(h). We note that the small upturn in dR/dT at low

temperature comes from the rapid decreasing of R due to the superconducting transition at T_c . A sign change in dR/dT is necessary for well-defined T_N and T_s . From the transport data in figures 3 and 4, we sketch the phase diagram for the samples with Ni dopings x = 0.049, 0.066, 0.082 and 0.098 in figure 5. For the underdoped compounds with x = 0.049 and 0.066, T_N and T_s are essentially independent of the Cr substitution. By increasing Cr impurity into the optimal doped sample x = 0.082, T_N drops from 30 K to 20 K, and then increases after the suppression of superconductivity. There may be a weak AF order with $T_N = 5.5$ K in the compound with x = 0.098 and y = 0.033 [figure 4(i)], suggesting the competing states between AF order and superconductivity in this system. Neutron scattering experiments in these materials are currently underway to confirm this conclusion. We also note that high doping of Cr into the parent compound BaFe₂As₂ could also suppress the AF order without change of ordered moments [31, 33]. Similar to $Ba(Fe_{1-x}Mn_x)_2As_2$ [34, 35], large Cr doping (>30%) changes the spin structure



Figure 4. (a)–(e) In-plane resistance up to 300 K for $BaFe_{2-x-y}Ni_xCr_yAs_2$. All data are normalized by the room temperature resistivity *R* (300 K), to remove uncertainty in estimates of the absolute value due to geometric factors. Each data set is offset vertically by 0.1 for clarity. (f)–(j) First order of derivative for the resistance. All curves are also normalized by the data at 300 K, where the arrows show antiferromagnetic transition temperature T_N and structure transition temperature T_s .

of the system from C-type to G-type [33]. Since the Cr concentrations in our $BaFe_{2-x-y}Ni_xCr_yAs_2$ samples are less than 2 %, we believe that the magnetic structure in the Cr-doped samples are the same as that of the undoped compounds. Moreover, in our recent collaborative measurements by Angle-Resolved-Photoemission-Spectroscopy (ARPES) and thermal conductivity, we have found the band structure and Fermi surfaces are barely changed upon doping Cr into $BaFe_{2-x}Ni_xAs_2$ with same Ni concentration, except for weak localization effects of charge carriers and suppression of T_c

[36]. These are consistent with our resistivity results and further confirm the impurity effects from Cr dopings.

4. Summary

In summary, we have carried out systematic transport and magnetic measurements on Cr-doped $BaFe_{2-x-y}Ni_xCr_yAs_2$ single crystals. We find that Cr-doping is very efficient in suppressing superconductivity and can be regarded as an



Figure 5. (a)Electronic phase diagram of BaFe_{2-x-y}Ni_xCr_yAs₂ for Ni doping x = 0.049, 0.066, 0.082 and 0.098 under different concentration of Cr impurity, where T_c^R and T_c^M mark the superconducting transition temperature determined by resistance and magnetization, respectively.

impurity instead of hole-doping. The AF ordering transition and structure transition in the underdoped samples are hardly affected by the small amount of Cr doping, while the antiferromagnetic correlations may be restored in optimally and overdoped samples when superconductivity is eliminated by Cr doping.

Acknowledgements

This work is supported by the National Science Foundation of China (No. 11374011), the Ministry of Science and Technology of China (973 projects: 2011CBA00110 and 2012CB821400), and The Strategic Priority Research Program (B) of the Chinese Academy of Sciences (Grant No. XDB07020300). The work at Rice is supported by NSF DMR-1362219 and the Robert A. Welch Foundation Grant No. C-1839. The authors thank the fruitful discussion with Tao Xiang, and the great help on the crystal characterization from Lihong Yang, Jun Zhu, Cong Ren and Xingjiang Zhou.

References

 Balatsky A V, Vekhter I and Zhu J X 2005 *Rev. Mod. Phys.* 78 373

- [2] Suchaneck A et al 2010 Phys. Rev. Lett. 105 037207
- [3] Kamihara Y, Watanabe T, Hirano M and Hosono H 2008 J. Am. Chem. Soc. 130 3296
- [4] de la Cruz C et al 2008 Nature (London) 453 899
- [5] Zhao J et al 2008 Nat. Mater. 7 953
- [6] Sefat A S, Jin R Y, McGuire M A, Sales B C, Singh D J and Mandrus D 2008 Phys. Rev. Lett. 101 117004
- [7] Huang Q et al 2008 Phys. Rev. Lett. 101 257003
- [8] Ni N et al 2010 Phys. Rev. B 82 024519
- [9] Chen Y C, Lu X Y, Wang M, Luo H Q and Li S L 2011 Supercond. Sci. Technol. 24 065004
- [10] Luo H Q et al 2012 Phys. Rev. Lett. 108 247002
- [11] Lu X Y et al 2013 Phys. Rev. Lett. 110 257001
- [12] Lu X Y et al 2014 Phys. Rev. B 90 024509
- [13] Pratt D K et al 2011 Phys. Rev. Lett. 106 257001
- [14] Yuan H Q, Singleton J, Balakirev F F, Baily S A, Chen G F, Luo J L and Wang N L 2009 Nature 457 565
- [15] Sebastian S E et al 2008 Nature 454 200
- [16] Xiao G, Cieplak M Z, Xiao J Q and Chien C L 1990 Phys. Rev. B 42 8752
- [17] Tallon J L, Bernhard C, Williams G V M and Loram J W 1997 Phys. Rev. Lett. 79 5294
- [18] Alloul H, Bobroff J, Gabay M and Hirschfeld P J 2009 Rev. Mod. Phys. 81 45
- [19] Cheng P, Shen B, Hu J P and Wen H-H 2010 Phys. Rev. B 81 174529
- [20] Guo Y F et al 2010 Phys. Rev. B 82 054506
- [21] Li J et al 2011 Phys. Rev. B 84 020513
- [22] Li J et al 2012 Phys. Rev. B 85 214509
- [23] Li J et al 2012 Solid State Commun. 152 671
- [24] Cheng P, Shen B, Han F and Wen H-H 2013 EPL 104 37007

- [25] Li Y K, Shen C Y, Luo Y K, Yang X J, Tao Q, Cao G-H and Xu Z-A 2013 EPL 102 37003
- [26] Inabe T, Kawamata T, Noji T, Adachi T and Koike Y 2013 J. Phys. Soc. Jap. 82 044712
- [27] Onari S and Kontani H 2009 Phys. Rev. Lett. 103 177001
- [28] Tarantini C et al 2010 Phys. Rev. Lett. 104 087002
- [29] Li Y, Tong J, Tao Q, Feng C, Cao G-H, Chen W, Zhang F and Xu Z-A 2010 New J. Phys. 12 083008
- [30] Luo H Q, Wang Z S, Yang H, Cheng P, Zhu X Y and Wen H-H 2008 Supercond. Sci. Technol. 21 125014
- [31] Sefat A S et al 2009 Phys. Rev. B 79 224524
- [32] Chu J H, Analytis J G, Kucharczyk C and Fisher I R 2009 Phys. Rev. B 79 014506
- [33] Marty K et al 2011 Phys. Rev. B 83 060509
- [34] Singh Y, Green M A, Huang Q, Kreyssig A, McQueeney R J, Johnston D C and Goldman A I 2009 Phys. Rev. B 80 100403
- [35] Pandey A, Anand V K and Johnston D C 2011 Phys. Rev. B 84 014405
- [36] Zhang R et al 2014 unpublished.